DB301S THRU DB307S

SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

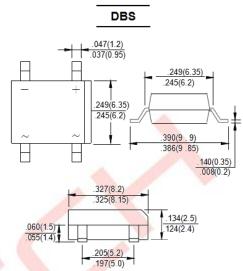
Reverse Voltage: 50 to 1000 V Rectified Output Current: 3A

FEATURES

- Rating to 1000V PRV
- Ldeal for printed circuit board
- Low forward voltage drop, high current capability
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- The plastic material has UL flammability classification 94V-0

MECHANICAL DATA

- Polarit: As marked on Body
- Weight: 0.02 ounces, 0.38 grams
- Mounting position:any



Dimensions in inches and (millimeters)

Dated:01/2020

Rev: 1.0

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter		Symbols	DB301S	DB302S	DB303S	DB304S	DB305S	DB306S	DB307S	Units
Maximum Repetitive Peak Reverse Voltage		V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage		V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage		V _{DC}	50	100	200	400	600	800	1000	V
Average Rectified Output Currentat TA = 40 °C		I _(AV)	3							Α
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)		I _{FSM}	60							А
Forward Voltage per element	at I _F = 3A	V _F				1.1				V
Maximum DC Reverse Current at Rated DC Blocking Voltage	@T _a =25 °C @T _a =125 °C	I _R	5.0 200					μА		
T <mark>ypi</mark> cal Junction Capacitance(Note1)		C _j	25							pF
T <mark>ypi</mark> cal Thermal Resistance (Note2)		$R_{\theta JA}$	40							°C/W
Operating and Storage Temperature Range		T_{j},T_{stg}	-55 ~ +150							°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

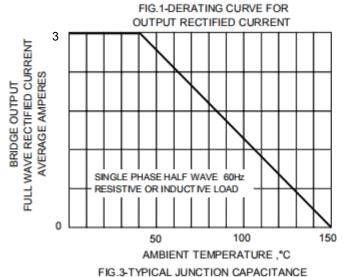
2.Thermal Resistance test performed in accordance with JESD-51. Unit mounted on 15mm*12mm81.6mm AL pad attach 195mm*110mm*10mm steel plate.

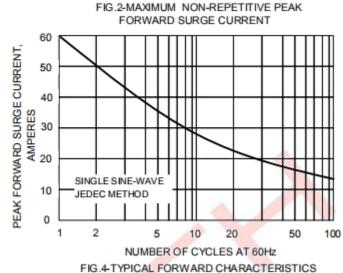
3. The typical data above is for reference only.

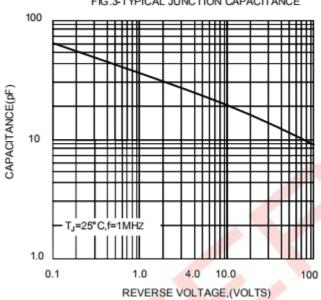


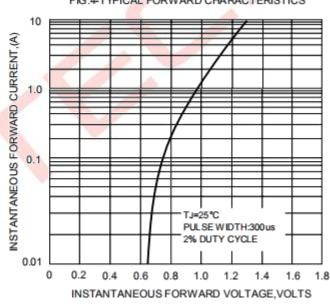
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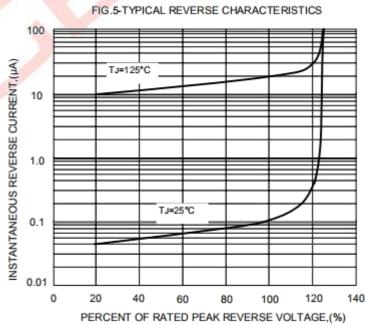
RATINGS AND CHARACTERISTIC CURVES













AGERTECH MICROELECTRONICS

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